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## Cascadable Silicon Bipolar MMIC Amplifier



# **Data Sheet**

### Description

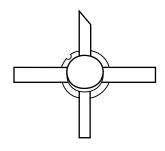
The MSA-0420 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a hermetic, high reliability package. This MMIC is designed for use as a general purpose  $50\Omega$  gain block. Typical applications include narrow and broad band IF and RF amplifiers in industrial and military applications.

The MSA-series is fabricated using Avago's 10 GHz  $f_T$ , 25 GHz  $f_{MAX}$ , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

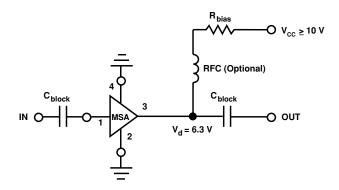
### **Features**

- Cascadable 50Ω Gain Block
- 3 dB Bandwidth: DC to 4.0 GHz
- 8.5 dB Typical Gain at 1.0 GHz
- 16.0 dBm Typical P<sub>1 dB</sub> at 1.0 GHz
- Unconditionally Stable (k>1)
- Hermetic Metal/Beryllia Microstrip Package

### 200 mil BeO Package



### **Typical Biasing Configuration**



MSA-0420 Absolute Maximum Ratings

Absolute Maximum <sup>[1]</sup>		
120 mA		
850 mW		
+13 dBm		
200°C		
−65 to 200°C		

Thermal Resistance<sup>[2,4]</sup>:

 $\theta_{jc} = 40^{\circ}\text{C/W}$ 

- 1. Permanent damage may occur if any of these limits are exceeded.

- T<sub>CASE</sub> = 25°C.
  Derate at 25 mW/°C for T<sub>C</sub> > 166°C.
  The small spot size of this technique results in a higher, though more accurate determination of q<sub>jc</sub> than do alternate methods.

# Electrical Specifications<sup>[1]</sup>, $T_A = 25^{\circ}C$

Symbol	Parameters and Test Conditions: $I_d = 90$	Units	Min.	Тур.	Max.	
G <sub>P</sub>	Power Gain ( S <sub>21</sub>   <sup>2</sup> )	f = 0.1 GHz	dB	7.5	8.5	9.5
$\DeltaG_P$	Gain Flatness	f = 0.1 to 2.5 GHz	dB		±0.6	±1.0
f <sub>3 dB</sub>	3 dB Bandwidth		GHz		4.3	
VSWR —	Input VSWR	f = 0.1 to 2.5 GHz			1.7:1	
	Output VSWR	f = 0.1 to 2.5 GHz			1.8:1	
NF	50 Ω Noise Figure	f = 1.0 GHz	dB		6.5	
P <sub>1 dB</sub>	Output Power at 1 dB Gain Compression	f = 1.0 GHz	dBm	14.0	16.0	
IP <sub>3</sub>	Third Order Intercept Point	f = 1.0 GHz	dBm		30.0	
t <sub>D</sub>	Group Delay	f = 1.0 GHz	psec		140	
V <sub>d</sub>	Device Voltage		V	5.7	6.3	6.9
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

<sup>1.</sup> The recommended operating current range for this device is 40 to 110 mA. Typical performance as a function of current is on the following page.

MSA-0420 Typical Scattering Parameters (Z  $_0$  = 50  $\Omega,$   $T_A$  = 25°C,  $I_d$  = 90 mA)

Freq.	S <sub>1</sub>	S <sub>21</sub>				S <sub>12</sub>			S <sub>22</sub>		
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	
0.1	.25	177	8.6	2.70	175	-16.4	.151	1	.03	-30	
0.2	.25	173	8.6	2.69	170	-16.5	.150	1	.04	-59	
0.4	.24	167	8.6	2.69	159	-16.5	.150	-1	.07	-79	
0.6	.22	160	8.5	2.67	149	-16.4	.152	-2	.10	-92	
0.8	.21	154	8.5	2.66	139	-16.3	.154	-2	.13	-99	
1.0	.20	148	8.3	2.60	129	-16.1	.156	-3	.16	-109	
1.5	.14	136	8.1	2.54	104	-15.6	.166	-4	.22	-124	
2.0	.10	136	7.9	2.48	80	-14.8	.181	-6	.25	-139	
2.5	.08	161	7.4	2.34	62	-14.3	.193	-5	.28	-147	
3.0	.10	178	7.0	2.24	39	-13.7	.206	-11	.31	-157	
3.5	.13	176	6.6	2.13	18	-12.6	.233	-18	.34	-167	
4.0	.14	163	5.9	1.97	-3	-11.9	.253	-25	.36	-176	
4.5	.14	133	5.3	1.83	-23	-11.3	.273	-33	.37	174	
5.0	.16	91	4.5	1.69	-343	-10.5	.299	-43	.37	162	

## Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

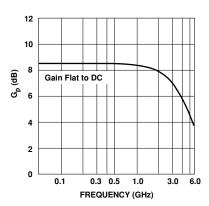


Figure 1. Typical Power Gain vs. Frequency,  ${\rm T_A} = 25^{\circ}{\rm C}$ ,  ${\rm I_d} = 90$  mA.

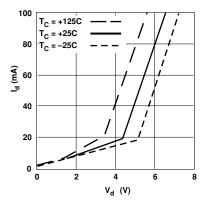


Figure 2. Device Current vs. Voltage.

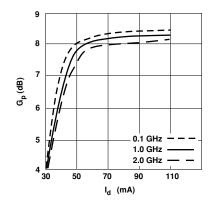


Figure 3. Power Gain vs. Current.

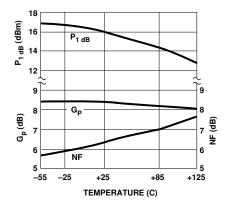


Figure 4. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, f = 1.0 GHz,  $\rm I_d$  = 90 mA.

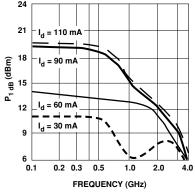


Figure 5. Output Power at 1 dB Gain Compression vs. Frequency.

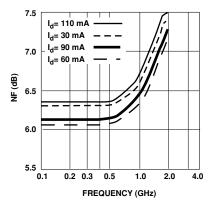
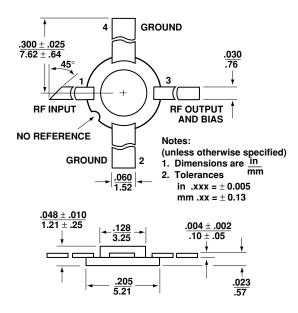


Figure 6. Noise Figure vs. Frequency.

### **Ordering Information**

Part Numbers	No. of Devices	Comments
MSA-0420	100	Bulk

### 200 mil BeO Package Dimensions



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